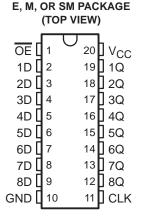
CD74FCT574 BiCMOS OCTAL EDGE-TRIGGERED D-TYPE FLIP-FLOP WITH 3-STATE OUTPUTS

SCBS745 - JULY 2000

- BiCMOS Technology With Low Quiescent Power
- Buffered Inputs
- Noninverted Outputs
- Input/Output Isolation From V_{CC}
- Controlled Output Edge Rates
- 48-mA Output Sink Current
- Output Voltage Swing Limited to 3.7 V
- SCR Latch-Up-Resistant BiCMOS Process and Circuit Design
- 3-State Outputs Drive Bus Lines Directly
- Package Options Include Plastic Small-Outline (M) and Shrink Small-Outline (SM) Packages and Standard Plastic (E) DIP



description

The CD74FCT574 is an octal, D-type, edge-triggered flip-flop that features noninverted, 3-state outputs, designed specifically for driving highly capacitive or relatively low-impedance loads. The devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

This device uses a small-geometry BiCMOS technology. The output stage is a combination of bipolar and CMOS transistors that limits the output high level to two diode drops below V_{CC} . This resultant lowering of output swing (0 V to 3.7 V) reduces power-bus ringing [a source of electromagnetic interference (EMI)] and minimizes V_{CC} bounce and ground bounce and their effects during simultaneous output switching. The output configuration also enhances switching speed and is capable of sinking 48 mA.

The eight flip-flops enter data into their registers on the low-to-high transition of the clock (CLK). On the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels set up at the data (D) inputs.

The output-enable (\overline{OE}) input controls the 3-state outputs and is independent of the register operation. \overline{OE} can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The CD74FCT574 is characterized for operation from 0°C to 70°C.

FUNCTION TABLE (each flip-flop)

| | OUTPUT | | |
|----|------------|---|----------------|
| OE | CLK | D | Q |
| L | \uparrow | Н | Н |
| L | \uparrow | L | L |
| L | H or L | Χ | Q ₀ |
| Н | Χ | Χ | Z |



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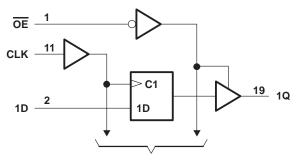


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logic symbol†

1 OE ΕN 11 CLK > C1 2 19 1D 1D ∇ 1Q 3 18 2D 2Q 4 17 3D 3Q 5 16 4D 4Q 6 15 5D **5Q** 7 14 6D 6Q 8 13 7D **7Q** 9 12 8D 8Q

logic diagram (positive logic)



To Seven Other Channels

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

| DC supply voltage range, V _{CC} | 0.5 V to 6 V |
|--|----------------|
| DC input clamp current, I_{IK} ($V_I < -0.5 \text{ V}$) | |
| DC output clamp current, I _{OK} (V _O < -0.5 V) | |
| DC output sink current per output pin, I _{OL} | 70 mA |
| DC output source current per output pin, I _{OH} | |
| Continuous current through V _{CC} , I _{CC} | |
| Continuous current through GND | 400 mA |
| Package thermal impedance, θ _{JA} (see Note 1): E package | 69°C/W |
| M package | 58°C/W |
| SM package | 70°C/W |
| Storage temperature range, T _{stg} | –65°C to 150°C |

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 2)

| | | MIN | MAX | UNIT |
|----------------|------------------------------------|------|------|------|
| VCC | Supply voltage | 4.75 | 5.25 | V |
| V_{IH} | High-level input voltage | 2 | | V |
| V_{IL} | Low-level input voltage | | 0.8 | V |
| VI | Input voltage | 0 | VCC | V |
| Vo | Output voltage | 0 | VCC | V |
| loh | High-level output current | | -15 | mA |
| loL | Low-level output current | | 48 | mA |
| Δt/Δν | Input transition rise or fall rate | 0 | 10 | ns/V |
| T _A | Operating free-air temperature | 0 | 70 | °C |
| | | | | |

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | Vaa | T _A = 25°C | | MIN | MAX | UNIT |
|--------------------|---|--------|-----------------------|------|--------|------|------|
| PARAMETER | TEST CONDITIONS | VCC | MIN | MAX | IVIIIV | WAX | UNIT |
| VIK | $I_{I} = -18 \text{ mA}$ | 4.75 V | | -1.2 | | -1.2 | V |
| Voн | I _{OH} = -15 mA | 4.75 V | 2.4 | | 2.4 | | V |
| V _{OL} | $I_{OL} = 48 \text{ mA}$ | 4.75 V | | 0.55 | | 0.55 | V |
| lį | $V_I = V_{CC}$ or GND | 5.25 V | | ±0.1 | | ±1 | μΑ |
| loz | $V_O = V_{CC}$ or GND | 5.25 V | | ±0.5 | | ±10 | μΑ |
| los† | $V_I = V_{CC}$ or GND, $V_O = 0$ | 5.25 V | -60 | | -60 | | mA |
| Icc | $V_I = V_{CC}$ or GND, $I_O = 0$ | 5.25 V | | 8 | | 80 | μΑ |
| Δl _{CC} ‡ | One input at 3.4 V, Other inputs at V _{CC} or GND | 5.25 V | | 1.6 | | 1.6 | mA |
| Ci | V _I = V _{CC} or GND | | | 10 | | 10 | pF |
| Co | $V_O = V_{CC}$ or GND | | | 15 | | 15 | pF |

[†] Not more than one output should be tested at a time, and the duration of the test should not exceed 100 ms.

timing requirements over recommended operating temperature conditions (unless otherwise noted) (see Figure 1)

| | MIN | MAX | UNIT | | |
|-----------------|----------------|------------------|------|--|----|
| fclock | | 70 | MHz | | |
| t _W | Pulse duration | CLK high or low | 7 | | ns |
| t _{su} | Setup time | Data before CLK↑ | 2 | | ns |
| t _h | Hold time | Data after CLK↑ | 2 | | ns |

switching characteristics over recommended operating temperature conditions (unless otherwise noted) (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | T _A = 25°C | MIN | MAX | UNIT |
|------------------|-----------------|----------------|-----------------------|-----|------|------|
| f _{max} | | | | 70 | | MHz |
| t _{pd} | CLK | Q | 6.6 | 2 | 10 | ns |
| t _{en} | ŌĒ | Q | 9 | 1.5 | 12.5 | ns |
| ^t dis | ŌĒ | Q | 6 | 1.5 | 8 | ns |

noise characteristics, V_{CC} = 5 V, C_L = 50 pF, T_A = 25°C

| | PARAMETER | MIN | TYP | MAX | UNIT |
|---------------------|---|-----|-----|-----|------|
| V _{OL(P)} | Quiet output, maximum dynamic V _{OL} | | 1 | | V |
| V _{OH(V)} | Quiet output, minimum dynamic V _{OH} | | 0.5 | | V |
| V _{IH} (D) | High-level dynamic input voltage | 2 | | | V |
| V _{IL(D)} | Low-level dynamic input voltage | | | 0.8 | V |

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

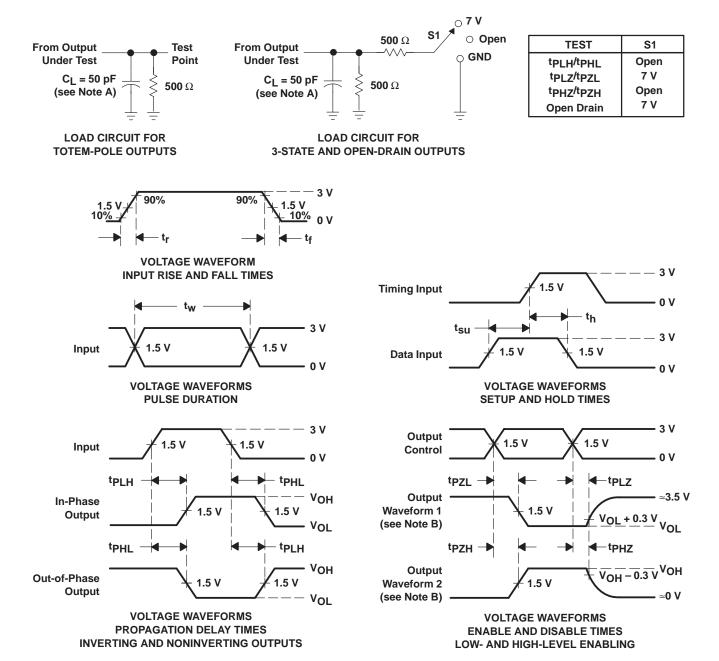
| | PARAMETER | TEST C | ONDITIONS | TYP | UNIT |
|--------------------|------------------------------|----------|-----------|-----|------|
| C _{pd} Po | ower dissipation capacitance | No load, | f = 1 MHz | 34 | pF |



[‡]This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, t_r and $t_f = 2.5$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. tpzL and tpzH are the same as ten.
- G. tpHL and tpLH are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms









11-Apr-2013

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package | Pins | Package | Eco Plan | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Top-Side Markings | Samples |
|------------------|----------|--------------|---------|------|---------|----------|------------------|---------------|--------------|-------------------|---------|
| | (1) | | Drawing | | Qty | (2) | | (3) | | (4) | |
| CD74FCT574E | OBSOLETE | PDIP | N | 20 | | TBD | Call TI | Call TI | 0 to 70 | | |
| CD74FCT574M | OBSOLETE | SOIC | DW | 20 | | TBD | Call TI | Call TI | 0 to 70 | | |
| CD74FCT574M96 | OBSOLETE | SOIC | DW | 20 | | TBD | Call TI | Call TI | 0 to 70 | | |
| CD74FCT574SM | OBSOLETE | SSOP | DB | 20 | | TBD | Call TI | Call TI | 0 to 70 | | |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

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⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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